

# SANYO Semiconductors **DATA SHEET**

An ON Semiconductor Company

# LV8405V — Bi-CMOS IC 2ch Forward/Reverse Motor Driver

#### Overview

LV8405T is a 2ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance  $(0.75\Omega \text{ typ})$  and current dissipation are low.

It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

#### **Functions**

- 2ch forward/reverse motor driver.
- Low power consumption.
- Low-temperature resistance  $0.75\Omega$ .

- Built-in low voltage reset and thermal shutdown circuit.
- Four mode function forward/reverse, brake, stop.
- Built-in charge pump.

## **Specifications**

**Maximum Ratings** at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (for load)	VM max		-0.5 to 16.0	V
Power supply voltage (for control)	V <sub>CC</sub> max		-0.5 to 6.0	٧
Output current	I <sub>O</sub> max		1.4	Α
Output peak current	I <sub>O</sub> peak	t ≤ 10ms	2.5	Α
Input voltage	V <sub>IN</sub> max		-0.5 to V <sub>CC</sub> +0.5	V
Allowable power dissipation	Pd max	Mounted on a specified board*	800	mW
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

<sup>\*</sup> Specified board : 114.3mm  $\times$  76.1mm  $\times$  1.6mm, glass epoxy board.

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### LV8405V

## Allowable Operating Conditions at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (VM pin)	VM		1.5 to 15.0	V
Power supply voltage (V <sub>CC</sub> pin)	Vcc		2.8 to 5.5	V
Input signal voltage	V <sub>IN</sub>		0 to V <sub>CC</sub>	V
Input signal frequency	f max		200	kHz

## Electrical Characteristics Ta = 25°C, V<sub>CC</sub> = 3.0V, VM = 6.0V, SGND = PGND = 0V, unless otherwise specified.

Parameter		Cymphol	Conditions	Remarks	Ratings			Unit
		Symbol	Conditions		min	typ	max	Unit
Standby load cu	Standby load current drain		V <sub>CC</sub> = 0V, VM = 6V	1			1.0	μА
Operating contro	ol current drain	IC1	When V <sub>CC</sub> is applied, with no load	2		0.85	1.2	mA
High-level input	voltage	VIH	2.7 ≤ V <sub>CC</sub> ≤ 5.5V		0.6×V <sub>CC</sub>		Vcc	V
Low-level input	voltage	V <sub>IL</sub>	$2.7 \le V_{CC} \le 5.5V$		0		0.2×V <sub>CC</sub>	V
	High-level input current (IN1, IN2, IN3, IN4)		IN1, IN2, IN3, IN4 = 3V	3		15	25	μА
Low-level input current (IN1, IN2, IN3, IN4)		Ιμ	IN1, IN2, IN3, IN4 = 0V	3	-1.0			μА
Pull-down resistance value (IN1-4)		RPD1			100	200	400	kΩ
Charge pump vo	Charge pump voltage		V <sub>CC</sub> + VM		8.5	9.0	9.5	V
Output ON resistance 1		RON1	Sum of top and bottom sides ON resistance.	4		0.75	1.2	Ω
Output ON resistance 2		RON2	Sum of top and bottom sides ON resistance. V <sub>CC</sub> = 2.8V	4		1.0	1.5	Ω
Low-voltage detection voltage		VCS	V <sub>CC</sub> pin voltage is monitored	5	2.15	2.30	2.45	V
Thermal shutdown temperature		Tth	Design guarantee value *	6	150	180	210	°C
Output block Turn-on time		TPLH		7		0.2	0.4	μS
	Turn-off time	TPHL		7		0.2	0.4	μS

<sup>\*:</sup> Design guarantee value and no measurement is preformed.

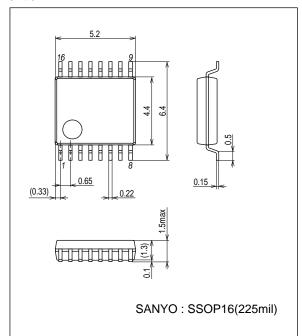
#### Remarks

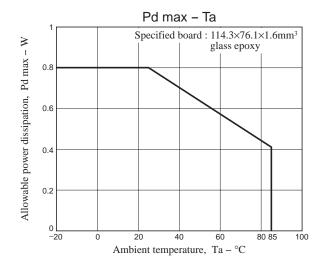
- 1. Current consumption when output at the VM pin is off.
- 2. Current consumption at the V<sub>CC</sub> pin when V<sub>CC</sub> is 3V and IN1 to IN4 are all 0V (standby mode).
- 3. Pins IN 1, 2, 3, and 4 are all pulled down.
- 4. Sum of upper and lower saturation voltages of OUT pin divided by the current.
- 5. All power transistors are turned off if a low  $V_{\hbox{\footnotesize{CC}}}$  condition is detected.
- 6. All output transistors are turned off if the thermal protection circuit is activated. They are turned on again as the temperature goes down.
- 7. Rising time from 10 to 90% and falling time from 90 to 10% are specified.

# **Package Dimensions**

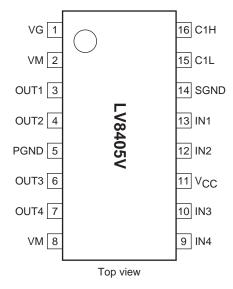
unit: mm (typ)

3178B

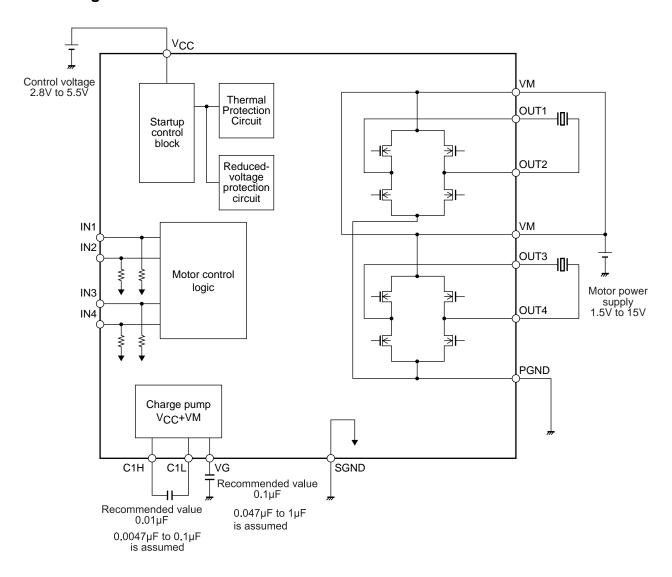




# **Pin Assignment**



## **Block Diagram**



\* Connect a kickback absorption capacitor as near as possible to the IC. Coil kickback may cause increase in VM line voltage, and a voltage exceeding the maximum rating may be applied momentarily to the IC, which results in deterioration or damage of the IC

## **Truth Table**

IN1 (IN3)	IN2 (IN4)	OUT1 (OUT3)	OUT2 (OUT4)	Charge pump	Mode
Н	Н	Z	Z	ON	Standby
Н	L	L	Н		Reverse
L	Н	Н	L		Forward
L	L	L	L		Brake

- : denotes a don't care value. Z : High-impedance

- $\bullet$  The charge pump is always activated as long as  $V_{\hbox{\footnotesize{CC}}}$  is applied.
- \* All power transistors turn off and the motor stops driving when the IC is detected in low voltage or thermal protection mode.

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#### **Pin Functions**

Pin No.	Pin name	Description	Equivalent circuit
16 1	C1H VG	Step-up capacitor connection pin.	C1H VG
13 12 10 9	IN1 IN2 IN3 IN4	Driver output switching. (Pull-down resistor incorporated)	VCC 1kΩ 1kΩ 200kΩ
3 4 6 7	OUT1 OUT2 OUT3 OUT4	Driver output.	OUT OUT OUT PGND
2 8	VM	Motor block power supply.	
11	V <sub>CC</sub>	Logic block power supply.	
14	SGND	Control block ground.	
5	PGND	Driver block ground.	
-			

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